

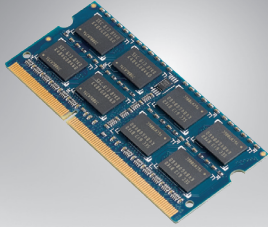
SQR-SD4N/SQR-SD4I

SODIMM DDR4 3200

SQR-SD4N/SQR-SD4I (ECC)

ECC SODIMM DDR4 3200

NEW



RoHS
COMPLIANT
2002/95/EC

CE FCC

Features

- High data transfer rate up to 3200 MT/s
- Original Samsung IC chip
- Capacity up to 32GB
- Thermal sensor built-in
- Wide temperature support

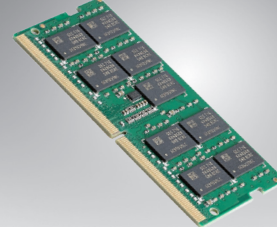
Specifications

DDR Type	DDR4
Pin / DIMM	260pin SODIMM
Data Transfer Rate	3200 MT/s
Golden Finger	30u"
Capacity	8GB/16G/32GB
Power Supply	1.2V (1.26V~1.14V)
Operating Temperature	0 ~ 85 °C/-40 ~ 85 °C
Dimensions (mm)	69.6 x 30 ± 0.13

Ordering Information

PN	Description
SQR-SD4N8G3K2SNBCB	260pin SODIMM DDR4 3200 8GB 1.2v 1Gx8 (0 ~ 85 °C) SAM
SQR-SD4N16G3K2SNCB	260pin SODIMM DDR4 3200 16GB 1.2v 1Gx8 (0 ~ 85 °C) SAM
SQR-SD4N32G3K2SNAB	260pin SODIMM DDR4 3200 32GB 1.2v 2Gx8 (0 ~ 85 °C) SAM
SQR-SD4I8G3K2SNBCB	260pin SODIMM DDR4 3200 8GB 1.2v 1Gx8 (-40 ~ 85 °C) SAM
SQR-SD4I16G3K2SNCB	260pin SODIMM DDR4 3200 16GB 1.2v 1Gx8 (-40 ~ 85 °C) SAM
SQR-S4I32G3K2SNAB	260pin SODIMM DDR4 3200 32GB 1.2v 2Gx8 (-40 ~ 85 °C) SAM

NEW



RoHS
COMPLIANT
2002/95/EC

CE FCC

Features

- High data transfer rate up to 3200 MT/s
- Original Samsung IC chip
- Capacity up to 32GB
- Thermal sensor built-in
- ECC function support

Specifications

DDR Type	DDR4
Pin / DIMM	260pin ECC SODIMM
Data Transfer Rate	3200 MT/s
Golden Finger	30u"
Capacity	8GB/16G/32GB
Power Supply	1.2V (1.26V~1.14V)
Operating Temperature	0 ~ 85 °C / -40 ~ 85 °C
Dimensions (mm)	69.6 x 30 ± 0.13

Ordering Information

PN	Description
SQR-SD4N8G3K2SEBCB	260pin ECC SODIMM DDR4 3200 8GB 1.2v 1Gx8 (0 ~ 85 °C) SAM
SQR-SD4N16G3K2SECB	260pin ECC SODIMM DDR4 3200 16GB 1.2v 1Gx8 (0 ~ 85 °C) SAM
SQR-SD4N32G3K2SEAB	260pin ECC SODIMM DDR4 3200 32GB 1.2v 2Gx8 (0 ~ 85 °C) SAM
SQR-SD4I8G3K2SEBCB	260pin ECC SODIMM DDR4 3200 8GB 1.2v 1Gx8 (-40 ~ 85 °C) SAM
SQR-SD4I16G3K2SECB	260pin ECC SODIMM DDR4 3200 16GB 1.2v 1Gx8(-40 ~ 85 °C) SAM
SQR-SD4I32G3K2SEAB	260pin ECC SODIMM DDR4 3200 32GB 1.2v 2Gx8(-40 ~ 85 °C) SAM